NSN 5962-01-358-9640

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-358-9640 **Body Length:** 1.490 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.217 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and programmed and electrostatic sensitive and monolithic and ultraviolet erasable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** D-10 mil-m-38510 Voltage Rating And Type Per Characteristic: -0.6 volts power source and 6.0 volts power source **Time Rating Per Chacteristic:** 350.00 nanoseconds access **Memory Device Type:** Prom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig:

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Yes - demil/mli